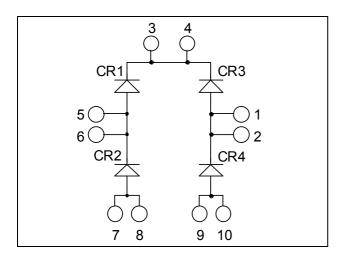
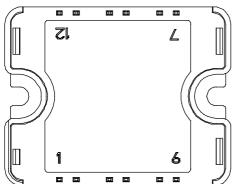


APTDF100H601G

Fast Diode Full Bridge Power Module





All multiple inputs and outputs must be shorted together 3/4; 5/6; 7/8; 1/2; 9/10

Absolute maximum ratings

Symbol Max ratings Parameter Unit VR Maximum DC reverse Voltage 600 V V_{RRM} Maximum Peak Repetitive Reverse Voltage 135 * $T_C = 25^{\circ}C$ Maximum Average Forward Duty cycle = 50%I_{F(AV)} Current $T_C = 80^{\circ}C$ 100 * А $T_C = 45^{\circ}C$ Non-Repetitive Forward Surge Current 8.3ms 500 I_{FSM}

* Specification of diode device but output current must be limited to 75A to not exceed a delta of temperature greater than 30°C for the connectors.

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

$V_{RRM} = 600V$ $I_{C} = 100A^{*}$ (*a*) $T_{C} = 80^{\circ}C$

$I_{\rm C} = 100 A$ @ $I_{\rm C} = 8$

Application

- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

Features

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant



All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

| Symbol | Characteristic | Test Conditions | Min | Тур | Max | Unit | |
|-----------------|---------------------------------|---------------------------|------------------------|-----|-----|------|----|
| $V_{\rm F}$ | Diode Forward Voltage | $I_F = 100A$ | | | 1.6 | 2.0 | |
| | | $I_F = 200A$ | | | 2.0 | | V |
| | | $I_{\rm F} = 100 {\rm A}$ | $T_{j} = 125^{\circ}C$ | | 1.3 | | |
| I _{RM} | Maximum Reverse Leakage Current | $V_{\rm p} = 600 V$ | $T_j = 25^{\circ}C$ | | | 250 | A |
| | | | $T_{j} = 125^{\circ}C$ | | | 500 | μA |
| CT | Junction Capacitance | $V_R = 200V$ | | | 190 | | pF |

Dynamic Characteristics

| Symbol | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|------------------|--------------------------|---|------------------------|-----|------|-----|------|
| t _{rr} | Reverse Recovery Time | $I_{F} = 100A$ $V_{R} = 400V$ $di/dt = 200A/\mu s$ | $T_j = 25^{\circ}C$ | | 160 | | ns |
| ۲r | | | $T_{j} = 125^{\circ}C$ | | 220 | | |
| Q _{rr} | Reverse Recovery Charge | | $T_j = 25^{\circ}C$ | | 290 | | nC |
| Qrr | | | $T_{j} = 125^{\circ}C$ | | 1530 | | пс |
| I | Reverse Recovery Current | | $T_j = 25^{\circ}C$ | | 5 | | А |
| I _{RRM} | | | $T_{j} = 125^{\circ}C$ | | 13 | | Π |
| t _{rr} | Reverse Recovery Time | $I_F = 100A$ $V_R = 400V$ $di/dt = 1000A/\mu s$ | | | 100 | | ns |
| Qrr | Reverse Recovery Charge | | $T_j = 125^{\circ}C$ | | 2890 | | nC |
| I _{RRM} | Reverse Recovery Current | | | | 44 | | А |

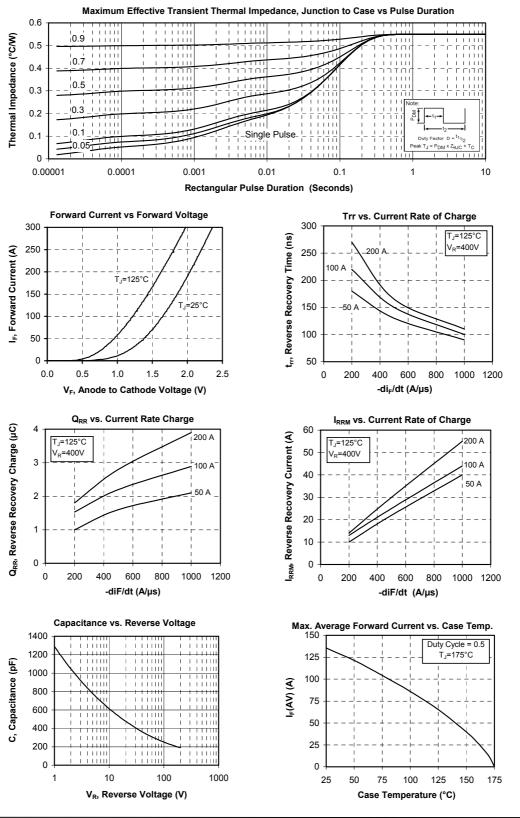
Thermal and package characteristics

| Symbol | Characteristic | | | Min | Тур | Max | Unit |
|-------------------|---|-------------|----|------|-----|------|------|
| R _{thJC} | Junction to Case Thermal Resistance | | | | | 0.55 | °C/W |
| V _{ISOL} | RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz | | | 4000 | | | V |
| T _J | Operating junction temperature range | | | -40 | | 175 | °C |
| T _{STG} | Storage Temperature Range | | | -40 | | 125 | |
| T _C | Operating Case Temperature | | | -40 | | 100 | |
| Torque | Mounting torque | To heatsink | M4 | 2 | | 3 | N.m |
| Wt | Package Weight | | | | | 80 | g |



APTDF100H601G

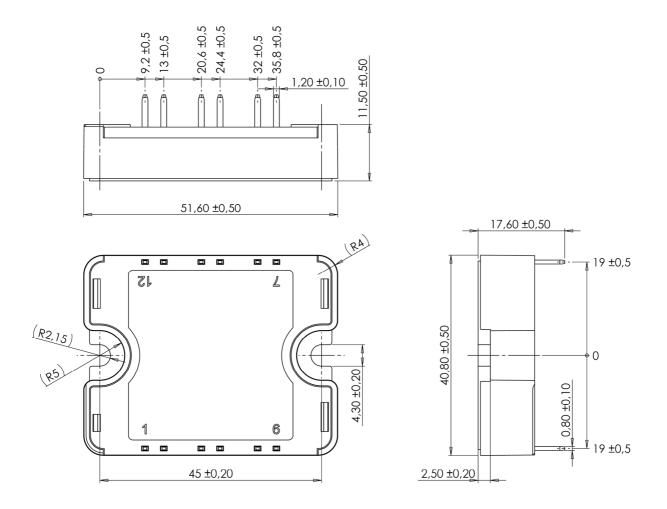
Typical Performance Curve



APTDF100H601G - Rev 1 October, 2012



SP1 Package outline (dimensions in mm)



See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com



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